

Amendments to the Claims:

The following listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Previously Presented) A thin film transistor including a plurality of component parts, comprising:
 - a channel region;
 - a gate electrode opposed to the channel region;
 - a gate insulating film provided between the channel region and the gate electrode;
 - a source-drain region connected to said channel region;
 - a source-drain wiring layer electrically connected to said source-drain region;
 - a gate wiring layer electrically connected to said gate electrode,
 - an extension of the gate electrode extending outwardly above and outside of the channel region; and
 - the extension extending in two directions from a central portion of the gate electrode.
- 2.-4. (Canceled)
5. (Original) A CMOS inverter circuit comprising two of the thin film transistors according to claim 1, the thin film transistors having an inverse conductivity type from each other, adjacent source-drain regions of said thin film transistors being connected.
6. (Original) A display device comprising a driving circuit including a thin film transistor according to claim 1.
7. (Original) An electronic apparatus comprising a display device as defined in claim 6.